

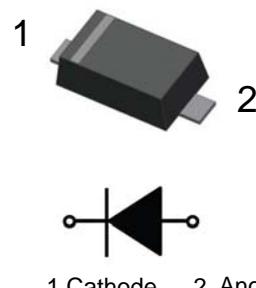


A1-A7

Features:

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Ideal for automated placement
- Lead free in comply with EU RoHS 2011/65/EU directives

SOD-123FL

**Absolute Maximum Ratings (Ta=25°C unless otherwise noted)**

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	A1	A2	A3	A4	A5	A6	A7	Units
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at T _c = 125 °C	I _{F(AV)}					1			A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I _{FSM}					30			A
Maximum Instantaneous Forward Voltage at 1 A	V _F				1.1				V
Maximum DC Reverse Current T _a = 25 °C at Rated DC Blocking Voltage T _a = 125 °C	I _R				5	50			µA
Typical Junction Capacitance ⁽¹⁾	C _j				8(TYP.)				pF
Typical Thermal Resistance ⁽²⁾	R _{θJA}				90				°C/W
Operating and Storage Temperature Range	T _j , T _{stg}				-55 ~ +150				°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Typical Characteristics

Fig.1 Forward Current Derating Curve

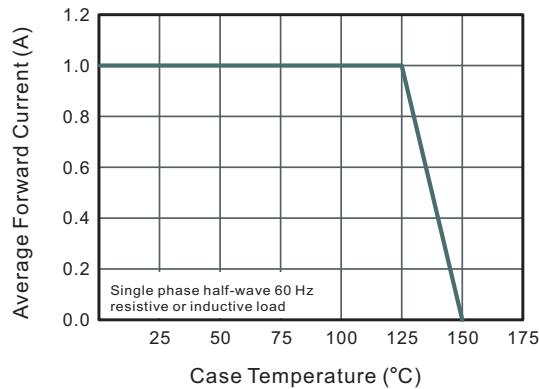


Fig.2 Typical Instantaneous Reverse Characteristics

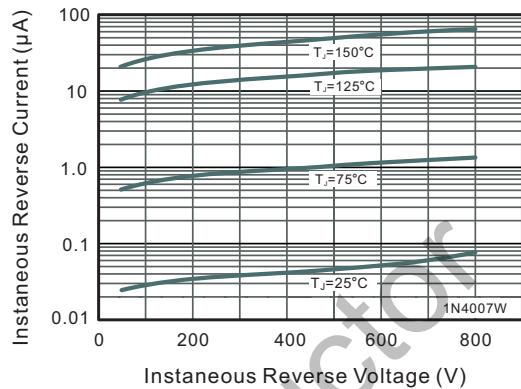


Fig.3 Typical Forward Characteristic

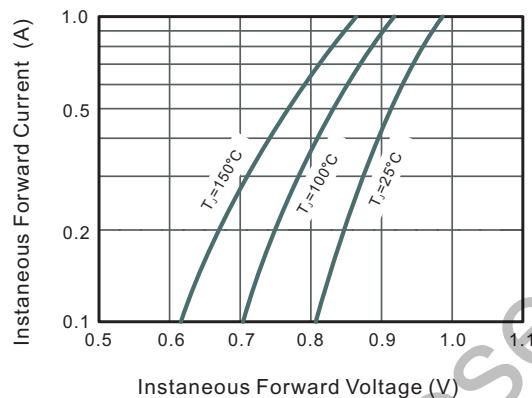


Fig.4 Typical Junction Capacitance

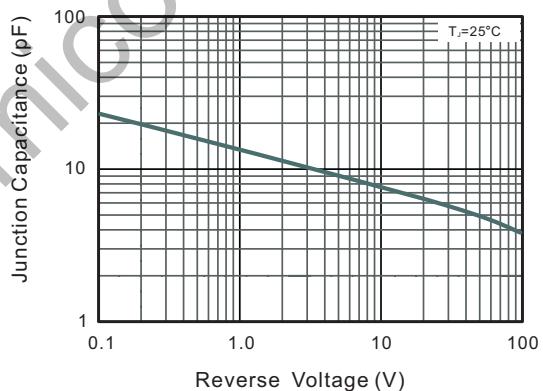
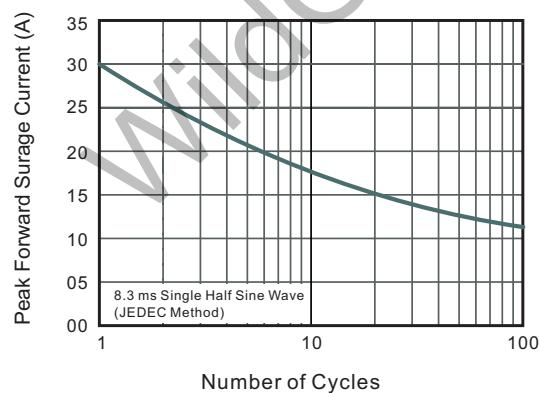
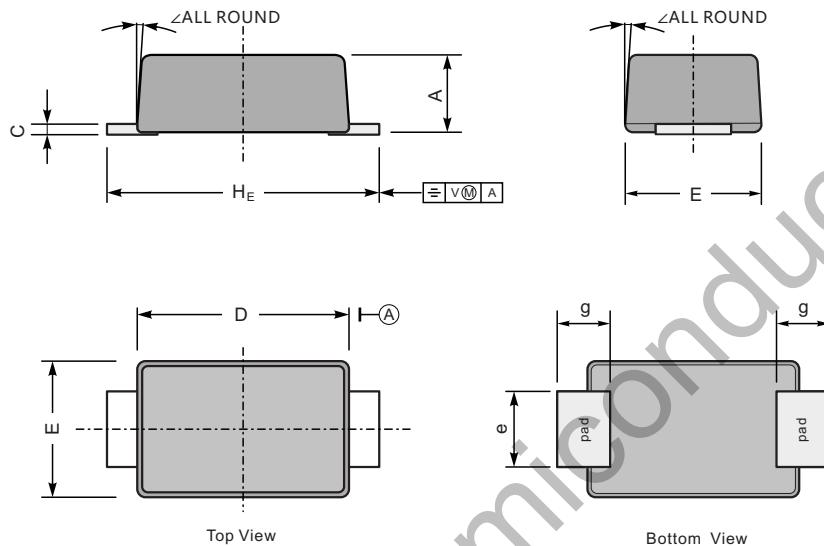


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

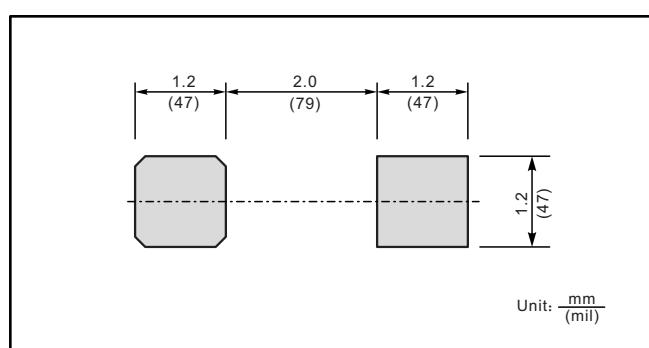


Package Dimension**SOD-123FL**

Unit: mm



UNIT		A	C	D	E	e	g	H_E	\angle
mm	max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	7°
	min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	max	43	7.9	114	75	43	35	150	7°
	min	35	4.7	102	67	31	28	138	

The recommended mounting pad sizeUnit: $\frac{\text{mm}}{(\text{mil})}$